Excellent Integrated System Limited

Stocking Distributor

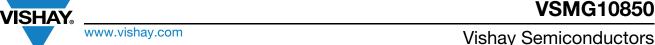
Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Opto Division</u> <u>VSMG10850</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Vishay Semiconductor/Opto Division: Excellent Integrated System Limited Datasheet of VSMG10850 - EMITTER IR 850NM 65MA SMD

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High Speed Infrared Emitting Diode, 850 nm, GaAlAs, DH



DESCRIPTION

VSMG10850 is an infrared, 850 nm side looking emitting diode in GaAlAs double hetero (DH) technology with high radiant power and high speed, molded in clear, untinted plastic package for surface mounting (SMD).

FEATURES

• Package type: Surface mount

• Package form: Side view

• Dimensions (L x W x H in mm): 3 x 2 x 1

• Peak wavelength: $\lambda_p = 850 \text{ nm}$

· High reliability

• High radiant power

· High radiant intensity

High speed

• Angle of half sensitivity: $\varphi = \pm 75^{\circ}$

• Low forward voltage

Package matches with detector VEMD10940F

• Floor life: 168 h, MSL 3, acclording to J-STD-020

• Lead (Pb)-free reflow soldering

 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

HALOGEN FREE

GREEN



- IR touch panel
- · High power emitter for low space applications
- High performance transmissive or reflective sensors

PRODUCT SUMMARY					
COMPONENT	I _e (mW/sr), 20 mA	φ (deg)	λ _p (nm)	t _r (ns)	
VSMG10850	1	± 75	850	15	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMG10850	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	side view	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V _R	5	V
Forward current		I _F	65	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	130	mA
Surge forward current	t _p = 100 μs	I _{FSM}	500	mA
Power dissipation		P _V	110	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	- 40 to + 85	°C
Storage temperature range		T _{stg}	- 40 to + 100	°C
Soldering temperature	according to fig. 9, J-STD-020	T _{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	450	K/W

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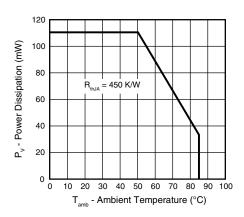
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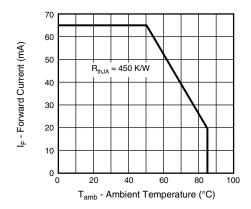


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	1.1	1.4	1.65	V
Forward voltage	$I_F = 65 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.45		V
	$I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$	V _F		1.9		V
Temperature coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			10	μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $E = 0 \text{ mW/cm}^2$	CJ		45		pF
	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	I _e	0.6	1	1.8	mW/sr
Radiant intensity	$I_F = 65 \text{ mA}, t_p = 20 \text{ ms}$	l _e		3.25		mW/sr
	$I_F = 500 \text{ mA}, t_p = 100 \mu \text{s}$	I _e		24		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе		40		mW
Temperature coefficient of radiant power	I _F = 1 mA	TKφ _e		- 1.1		%/K
Angle of half intensity - horizontal		Φh		± 77.5		deg
Angle of half intensity - vertical		φν		± 72.5		deg
Peak wavelength	I _F = 30 mA	λ_{p}		850		nm
Spectral bandwidth	I _F = 30 mA	Δλ		40		nm
Temperature coefficient of λ _p	I _F = 30 mA	TK_{\lambdap}		0.25		nm
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		20		ns
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		20		ns

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

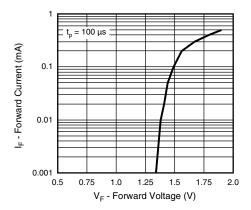


Fig. 3 - Forward Current vs. Forward Voltage

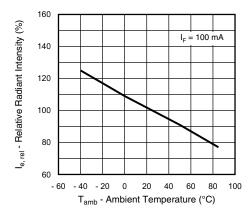


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

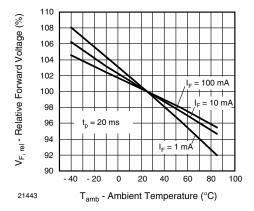


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

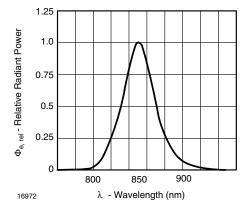


Fig. 7 - Relative Radiant Power vs. Wavelength

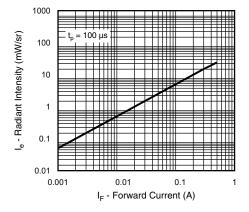


Fig. 5 - Radiant Intensity vs. Forward Current

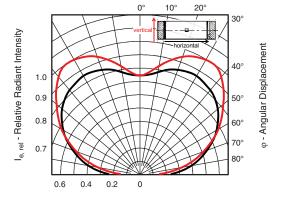


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

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REFLOW SOLDER PROFILE

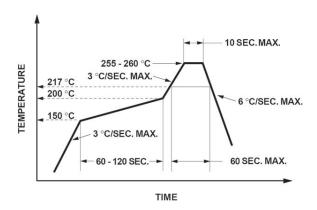


Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

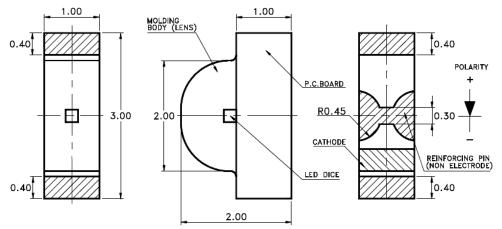
Conditions: T_{amb} < 30 °C, RH < 60 %

DRYING

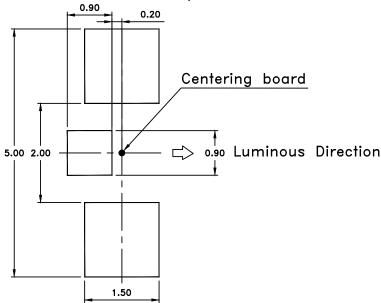
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

PACKAGE DIMENSIONS in millimeters

22701



Recommended Solder Pad Footprint



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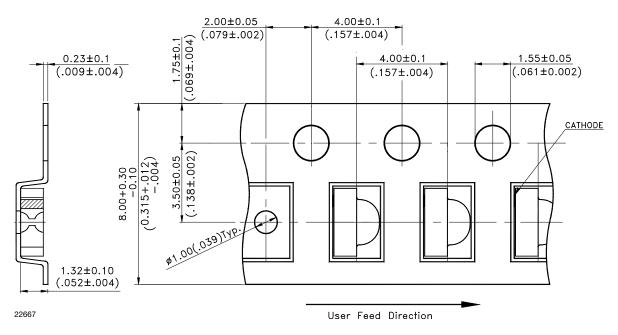
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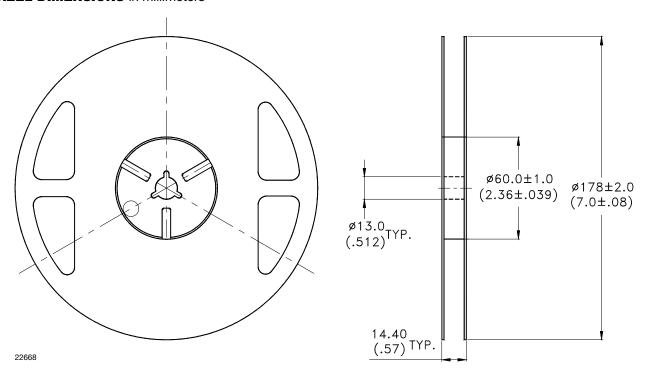
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BLISTER TAPE DIMENSIONS in millimeters



REEL DIMENSIONS in millimeters





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